



60EPU04  
60APU04

## Ultrafast Soft Recovery Diode

### Features

- Ultrafast Recovery
- 175°C Operating Junction Temperature

### Benefits

- Reduced RFI and EMI
- Higher Frequency Operation
- Reduced Snubbing
- Reduced Parts Count

$$t_{rr} = 50\text{ns (typ)}$$

$$I_{F(AV)} = 60\text{Amp}$$

$$V_R = 400\text{V}$$

### Description/ Applications

These diodes are optimized to reduce losses and EMI/ RFI in high frequency power conditioning systems. The softness of the recovery eliminates the need for a snubber in most applications. These devices are ideally suited for HF welding, power converters and other applications where switching losses are not significant portion of the total losses.

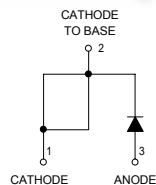
### Absolute Maximum Ratings

Parameters	Max	Units
$V_R$ Cathode to Anode Voltage	400	V
$I_{F(AV)}$ Continuous Forward Current, $T_C = 127^\circ\text{C}$	60	A
$I_{FSM}$ Single Pulse Forward Current, $T_C = 25^\circ\text{C}$	600	
$I_{FRM}$ ① Maximum Repetitive Forward Current	120	
$T_J, T_{STG}$ Operating Junction and Storage Temperatures	- 55 to 175	$^\circ\text{C}$

① Square Wave, 20kHz

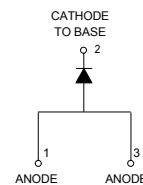
### Case Styles

60EPU04



TO-247AC (Modified)

60APU04



TO-247AC

**Electrical Characteristics @ T<sub>J</sub> = 25°C (unless otherwise specified)**

Parameters	Min	Typ	Max	Units	Test Conditions
V <sub>BR</sub> , V <sub>r</sub> Breakdown Voltage, Blocking Voltage	400	-	-	V	I <sub>R</sub> = 100μA
V <sub>F</sub> Forward Voltage	-	1.05	1.25	V	I <sub>F</sub> = 60A
	-	0.87	1.03	V	I <sub>F</sub> = 60A, T <sub>J</sub> = 175°C
	-	0.93	1.10	V	I <sub>F</sub> = 60A, T <sub>J</sub> = 125°C
I <sub>R</sub> Reverse Leakage Current	-	-	50	μA	V <sub>R</sub> = V <sub>R</sub> Rated
	-	-	2	mA	T <sub>J</sub> = 150°C, V <sub>R</sub> = V <sub>R</sub> Rated
C <sub>T</sub> Junction Capacitance	-	50	-	pF	V <sub>R</sub> = 400V
L <sub>S</sub> Series Inductance	-	3.5	-	nH	Measured lead to lead 5mm from package body

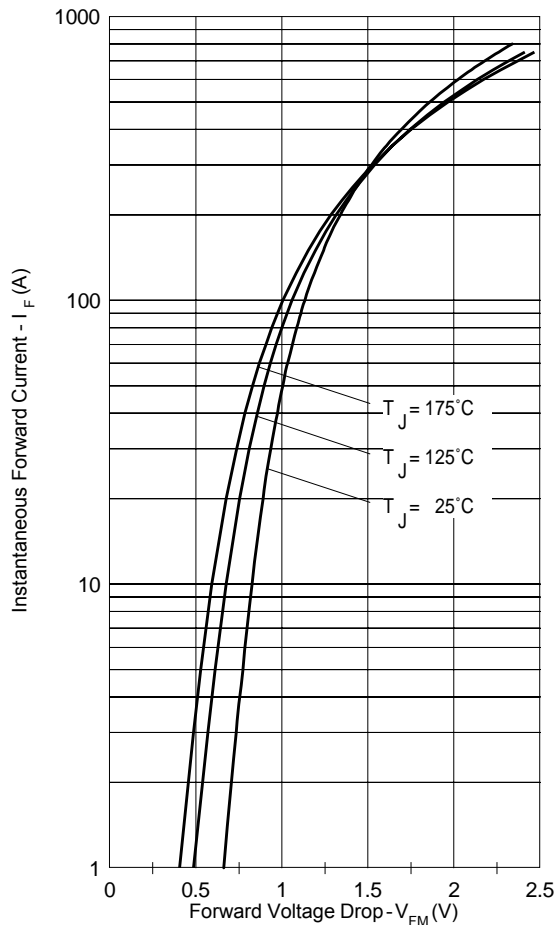
**Dynamic Recovery Characteristics @ T<sub>J</sub> = 25°C (unless otherwise specified)**

Parameters	Min	Typ	Max	Units	Test Conditions
t <sub>rr</sub> Reverse Recovery Time	-	50	60	ns	I <sub>F</sub> = 1A, di <sub>F</sub> /dt = 200A/μs, V <sub>R</sub> = 30V
	-	85	-		T <sub>J</sub> = 25°C
	-	145	-		T <sub>J</sub> = 125°C
I <sub>RRM</sub> Peak Recovery Current	-	8.8	-	A	T <sub>J</sub> = 25°C
	-	15.4	-		T <sub>J</sub> = 125°C
Q <sub>rr</sub> Reverse Recovery Charge	-	375	-	nC	T <sub>J</sub> = 25°C
	-	1120	-		T <sub>J</sub> = 125°C

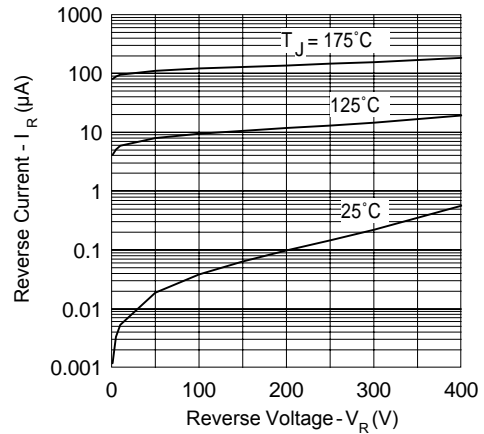
**Thermal - Mechanical Characteristics**

Parameters	Min	Typ	Max	Units
R <sub>thJC</sub> Thermal Resistance, Junction to Case			0.70	K/W
R <sub>thCS</sub> ② Thermal Resistance, Case to Heatsink		0.2		
Wt Weight		5.5		g
		0.2		(oz)
T Mounting Torque	1.2		2.4	N * m
	10		20	lbf.in

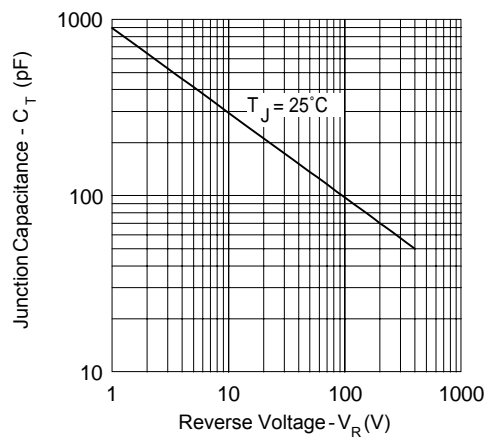
② Mounting Surface, Flat, Smooth and Greased



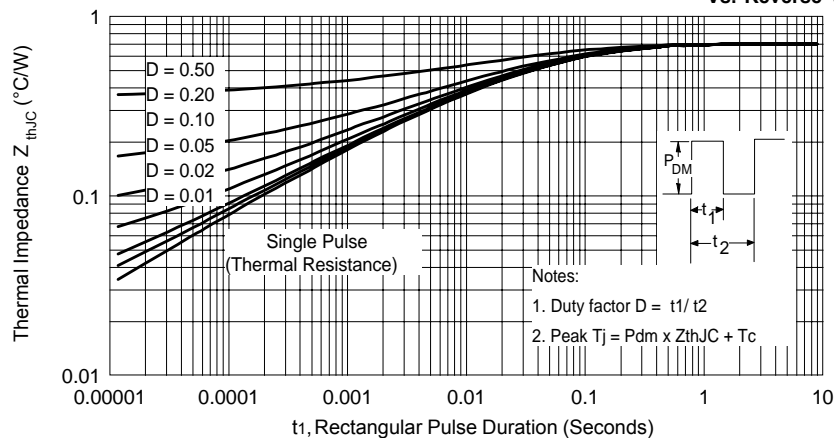
**Fig. 1 - Typical Forward Voltage Drop Characteristics**



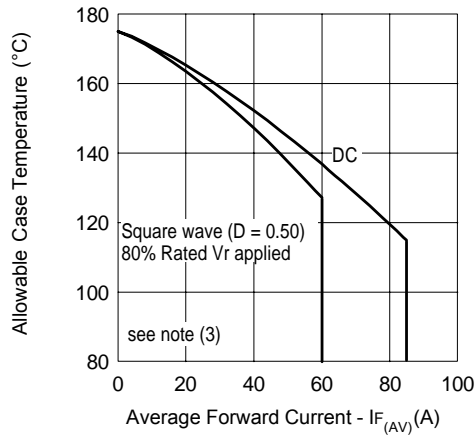
**Fig. 2 - Typical Values Of Reverse Current Vs. Reverse Voltage**



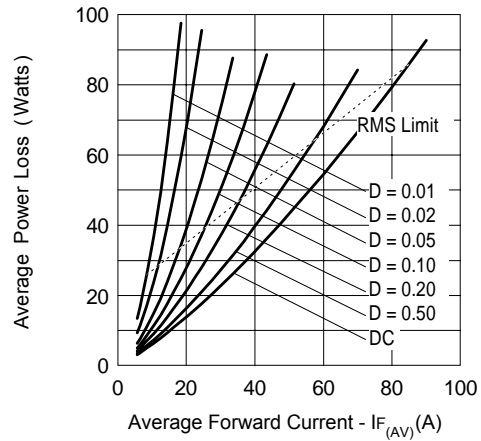
**Fig. 3 - Typical Junction Capacitance Vs. Reverse Voltage**



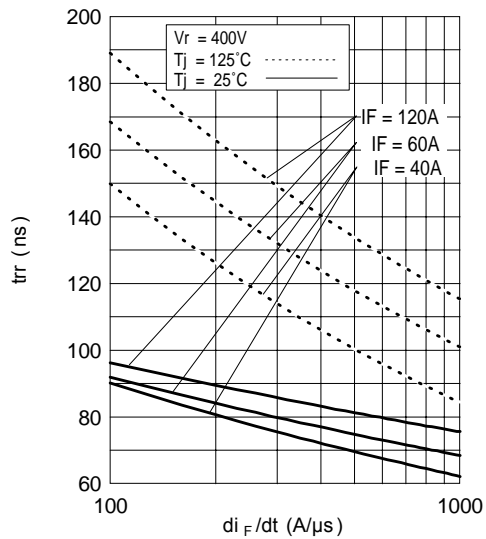
**Fig. 4 - Max. Thermal Impedance  $Z_{thJC}$  Characteristics**



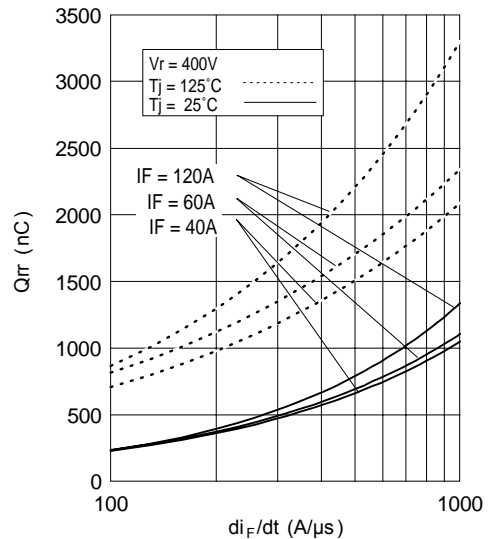
**Fig. 5 - Max. Allowable Case Temperature Vs. Average Forward Current**



**Fig. 6 - Forward Power Loss Characteristics**



**Fig. 7 - Typical Reverse Recovery time vs.  $di_F/dt$**

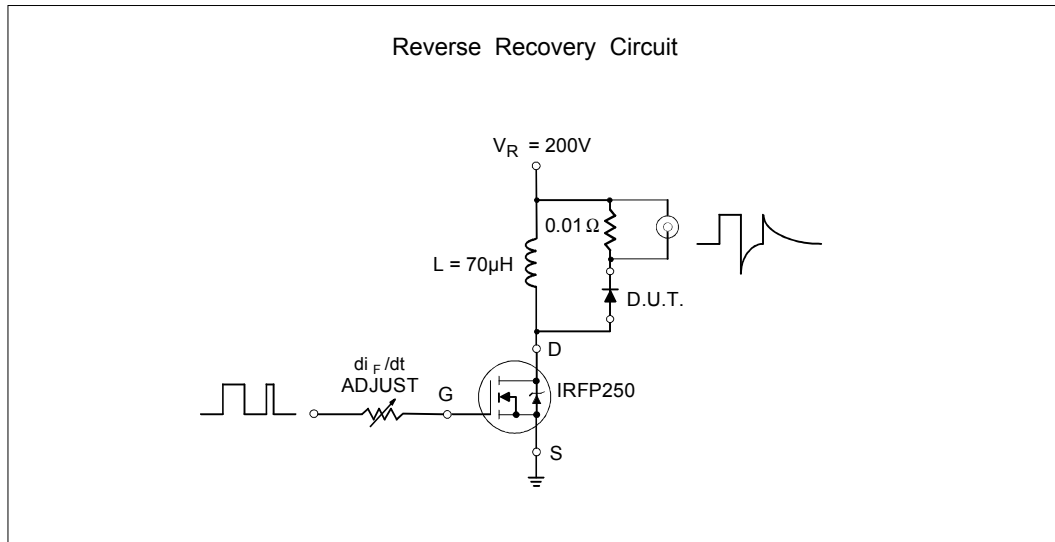


**Fig. 8 - Typical Stored Charge vs.  $di_F/dt$**

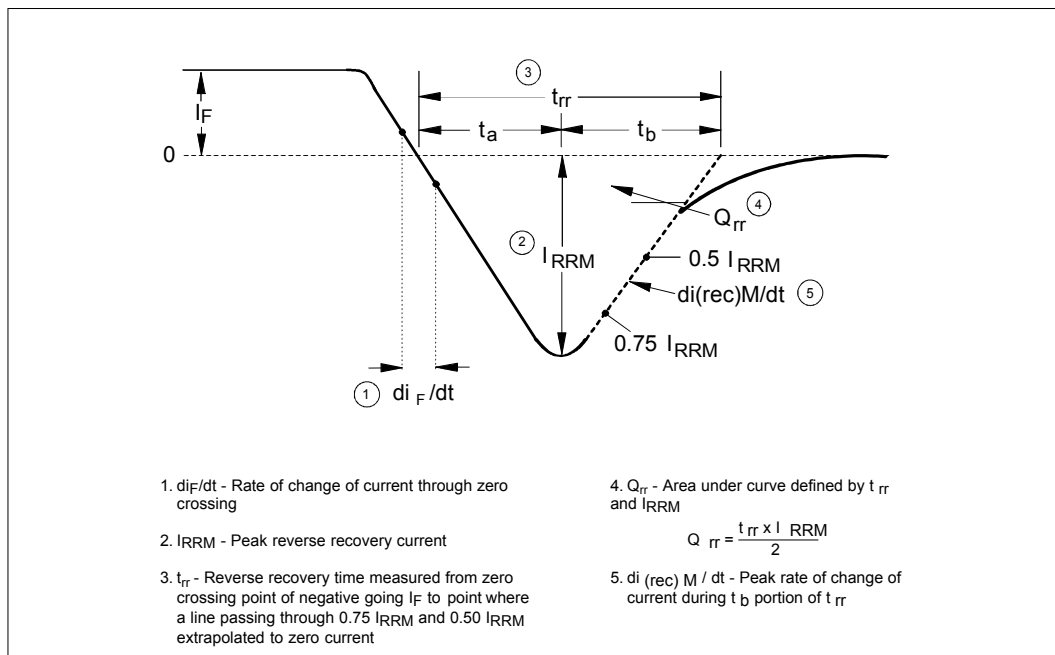
(3) Formula used:  $T_C = T_J - (P_d + P_{d_{REV}}) \times R_{thJC}$ ;

$P_d$  = Forward Power Loss =  $I_{F(AV)} \times V_{FM} @ (I_{F(AV)} / D)$  (see Fig. 6);

$P_{d_{REV}}$  = Inverse Power Loss =  $V_{R1} \times I_R (1 - D)$ ;  $I_R @ V_{R1} = 80\%$  rated  $V_R$

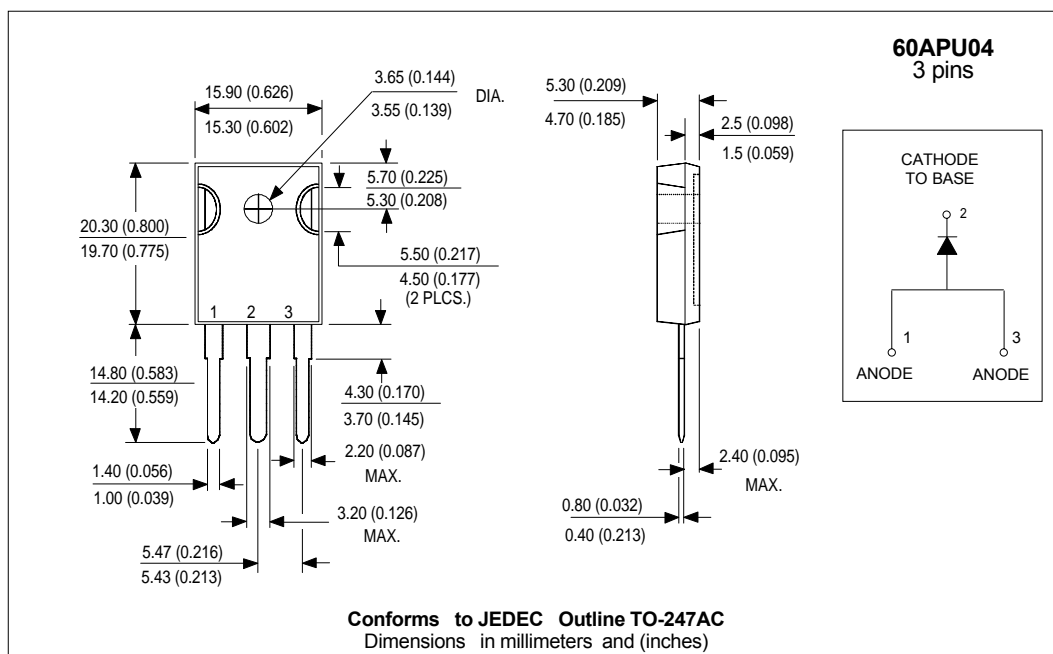
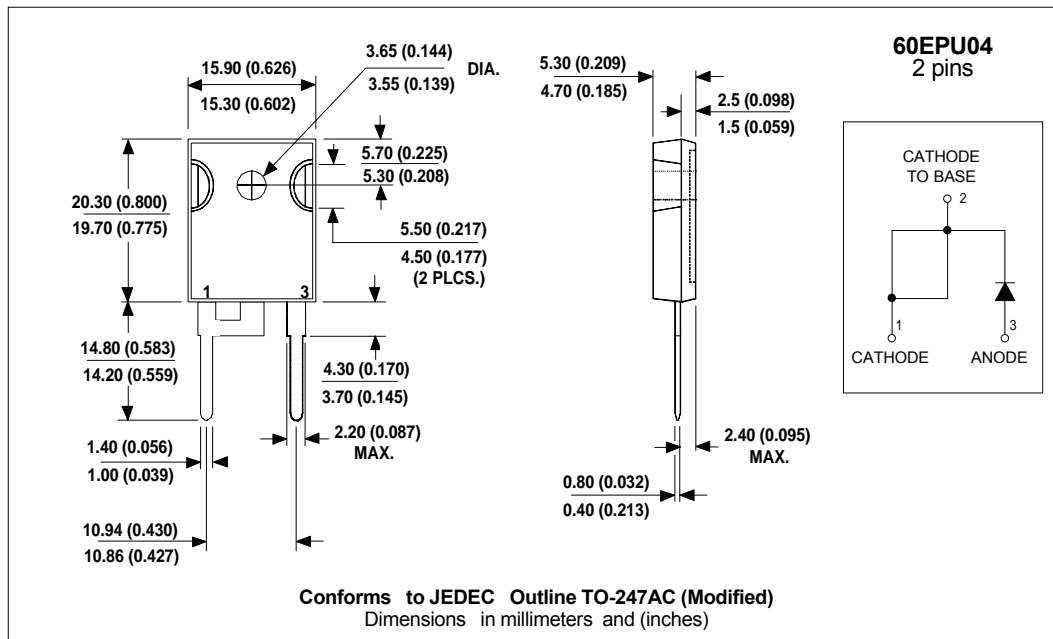


**Fig. 9- Reverse Recovery Parameter Test Circuit**



**Fig. 10 - Reverse Recovery Waveform and Definitions**

## Outline Table



## Ordering Information Table

Device Code				
60	E	P	U	04
1	2	3	4	5
1	-	Current Rating	(60 = 60A)	E = 2 pins A = 3 pins
2	-	Single Diode		
3	-	TO-247AC (Modified)		
4	-	Ultrafast Recovery		
5	-	Voltage Rating	(04 = 400V)	

Data and specifications subject to change without notice.  
This product has been designed and qualified for Industrial Level.  
Qualification Standards can be found on IR's Web site.

International  
**IR** Rectifier

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